

DERWENT-ACC-NO: 1992-067414

DERWENT-WEEK: 199951

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TITLE: Thin-film FET for memory - has source and
drain electrodes buried in insulation film between
upper gate electrode and film covering lower electrode
NoAbstract Dwg 1/9

PATENT-ASSIGNEE: CASIO COMPUTER CO LTD[CASK]

PRIORITY-DATA: 1990JP-0092021 (April 9, 1990)

| PATENT-FAMILY: | PUB-DATE | LANGUAGE |
|------------------|-------------------|----------|
| PUB-NO | | |
| PAGES MAIN-IPC | | |
| JP 03290970 A | December 20, 1991 | N/A |
| 005 N/A | | |
| JP 2969184 B2 | November 2, 1999 | N/A |
| 009 H01L 027/115 | | |

| APPLICATION-DATA: | APPL-DESCRIPTOR | APPL-NO |
|-------------------|-----------------|----------------|
| PUB-NO | | |
| APPL-DATE | | |
| JP 03290970A | N/A | 1990JP-0092021 |
| April 9, 1990 | | |
| JP 2969184B2 | N/A | 1990JP-0092021 |
| April 9, 1990 | | |
| JP 2969184B2 | Previous Publ. | JP 3290970 |
| N/A | | |

INT-CL (IPC): H01L021/8247, H01L027/11, H01L027/115, H01L029/78
H01L029/788, H01L029/792

ABSTRACTED-PUB-NO: JP 2969184B

EQUIVALENT-ABSTRACTS:

Optical disk having a resin substrate has a trench on the periphery when the resin substrates are adhered to each other. A groove or pit for tracking is formed on a side of a resin substrate. A 1st ceramics layer, a

recording

layer, 2nd ceramics layer and a reflection layer are laminated in order. The plates are adhered using epoxy gp. resin. A trench is formed at the periphery and a UV curing type resin is filled into the trench. The resin is cured and the periphery is cut.

ADVANTAGE - No change of mechanical characteristics at higher temp..

TITLE-TERMS: THIN FILM FET MEMORY SOURCE DRAIN ELECTRODE BURY
INSULATE FILM

UPPER GATE ELECTRODE FILM COVER LOWER ELECTRODE

NOABSTRACT

DERWENT-CLASS: U11 U12 U13 U14

EPI-CODES: U11-C18B5; U12-B03A; U12-D02A1; U12-Q; U13-C04B2; U14-
A03B7;

U14-H01A;

SECONDARY-ACC-NO:

Non-CPI Secondary Accession Numbers: N1992-050492